

## QUADRUPLE 2-INPUT NAND SCHMITT TRIGGER

The HEF4093B consists of four Schmitt-trigger circuits. Each circuit functions as a two-input NAND gate with Schmitt-trigger action on both inputs. The gate switches at different points for positive and negative-going signals. The difference between the positive voltage ( $V_p$ ) and the negative voltage ( $V_N$ ) is defined as hysteresis voltage ( $V_H$ ).

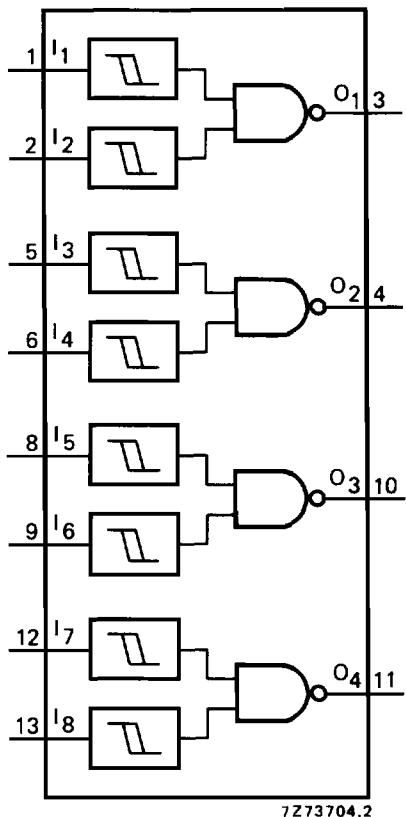


Fig. 1 Functional diagram.

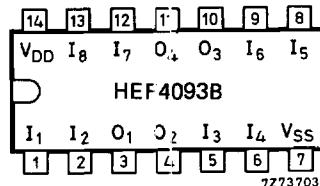


Fig. 2 Pinning diagram.

HEF4093BP(N): 14-lead DIL; plastic (SOT27-1)  
 HEF4093BD(F): 14-lead DIL; ceramic (cerdip) (SOT73)  
 HEF4093BT(D): 14-lead SO; plastic (SOT108-1)  
 ( ): Package Designator North America

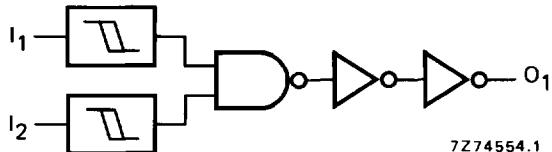


Fig. 3 Logic diagram (one gate).

## FAMILY DATA

I<sub>DD</sub> LIMITS category GATES

see Family Specifications

## D.C. CHARACTERISTICS

 $V_{SS} = 0 \text{ V}$ ;  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

	$V_{DD}$ V	symbol	min.	typ.	max.	
Hysteresis voltage	5	$V_H$	0,4	0,7	—	V
	10		0,6	1,0	—	V
	15		0,7	1,3	—	V
Switching levels positive-going input voltage	5	$V_P$	1,9	2,9	3,5	V
	10		3,6	5,2	7	V
	15		4,7	7,3	11	V
negative-going input voltage	5	$V_N$	1,5	2,2	3,1	V
	10		3	4,2	6,4	V
	15		4	6,0	10,3	V

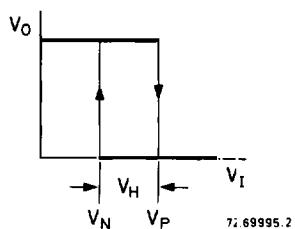
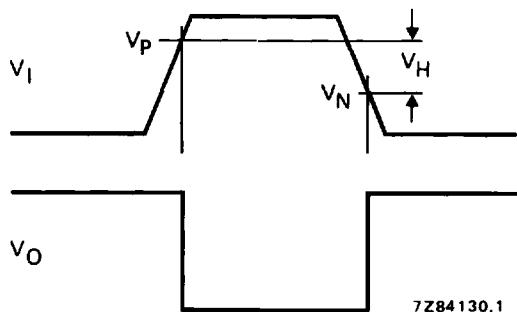


Fig. 4 Transfer characteristic.

Fig. 5 Waveforms showing definition of  $V_P$ ,  $V_N$  and  $V_H$ ; where  $V_N$  and  $V_P$  are between limits of 30% and 70%.

**A.C. CHARACTERISTICS** $V_{SS} = 0 \text{ V}$ ;  $T_{amb} = 25^\circ\text{C}$ ;  $C_L = 50 \text{ pF}$ ; input transition times  $\leq 20 \text{ ns}$ 

	$V_{DD}$ V	symbol	typ.	max.	typical extrapolation formula
Propagation delays $I_n \rightarrow O_n$ HIGH to LOW	5	t <sub>PHL</sub>	90	185	ns
	10		40	80	ns
	15		30	60	ns
	5	t <sub>PLH</sub>	85	170	ns
	10		40	80	ns
	15		30	60	ns
Output transition times	5	t <sub>THL</sub>	60	120	ns
	10		30	60	ns
	15		20	40	ns
	5	t <sub>TLH</sub>	60	120	ns
	10		30	60	ns
	15		20	40	ns

	$V_{DD}$ V	typical formula for P ( $\mu\text{W}$ )	where
Dynamic power dissipation per package (P)	5 10 15	$1300 f_i + \Sigma(f_o C_L) \times V_{DD}^2$ $6400 f_i + \Sigma(f_o C_L) \times V_{DD}^2$ $18700 f_i + \Sigma(f_o C_L) \times V_{DD}^2$	$f_i$ = input freq. (MHz) $f_o$ = output freq. (MHz) $C_L$ = load capacitance (pF) $\Sigma(f_o C_L)$ = sum of outputs $V_{DD}$ = supply voltage (V)

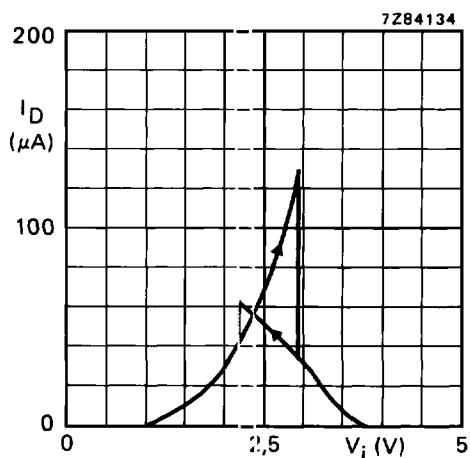


Fig. 6 Typical drain current as a function of input voltage;  $V_{DD} = 5\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

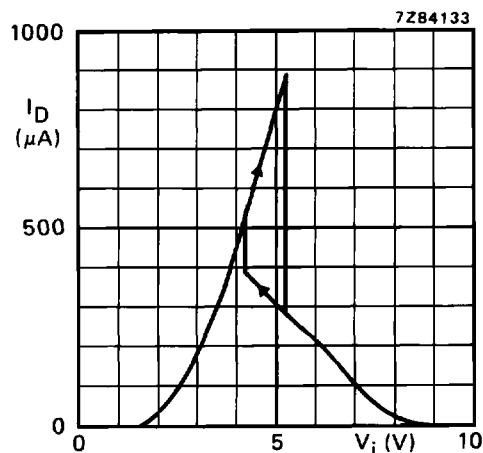


Fig. 7 Typical drain current as a function of input voltage;  $V_{DD} = 10\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

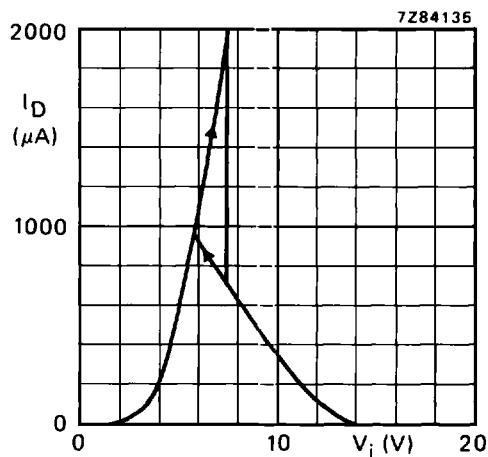


Fig. 8 Typical drain current as a function of input voltage;  $V_{DD} = 15\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

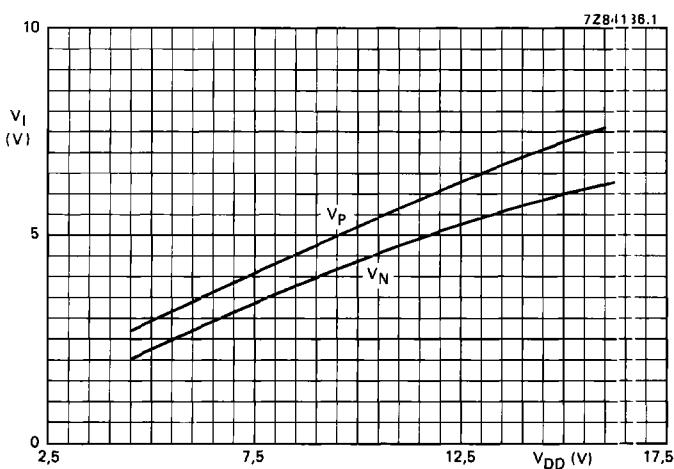


Fig. 9 Typical switching levels as a function of supply voltage  $V_{DD}$ ;  $T_{amb} = 25^{\circ}\text{C}$ .

## APPLICATION INFORMATION

Some examples of applications for the HEF4093B are:

- Wave and pulse shapers
- Astable multivibrators
- Monostable multivibrators.

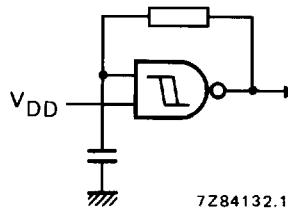


Fig. 10 The HEF4093B used as a astable multivibrator.

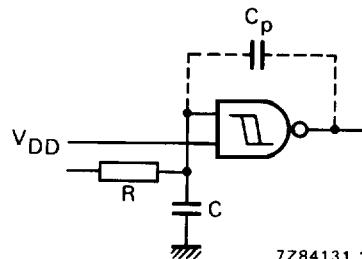


Fig. 11 Schmitt trigger driven via a high impedance ( $R > 1 \text{ k}\Omega$ ).

If a Schmitt trigger is driven via a high impedance ( $R > 1 \text{ k}\Omega$ ) then it is necessary to incorporate a capacitor  $C$  of such value that:  $\frac{C}{C_p} > \frac{V_{DD}-V_{SS}}{V_H}$ , otherwise oscillation can occur on the edges of a pulse.

$C_p$  is the external parasitic capacitance between inputs and output; the value depends on the circuit board layout.

#### Note

The two inputs may be connected together, but this will result in a larger through-current at the moment of switching.